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## Features

- 2 Differential Channel, 4:1 Mux/DeMux
- PCI Express® 2.0 performance, 5.0 Gbps
- Low Bit-to-Bit Skew, 7ps Max.
- Low Crosstalk: -23dB@3GHz
- Low Off Isolation: -23dB@3GHz
- $\mathrm{V}_{\mathrm{DD}}$ Operating Range: $+1.8 \mathrm{~V} \pm 10 \%$
- ESD Tolerance 2 kV HBM on data I/O
- Packaging ( Pb -free \& Green):
- 42 contact TQFN


## Block Diagram



## Description

Pericom Semiconductor's PI2PCIE2214 is a 8 to 2 differential channel multiplexer/demultiplexer switch. Due to its low bit-to-bit skew, high channel-to-channel noise isolation and high bandwidth, this product is ideal for PCI Express® switching to 5.0 Gbps.

## Application

Switch a PCI Express® lane output between four PCI Express lane inputs

## Pin Description



Truth Table

| SEL1 | SEL0 | FUNCTION |
| :---: | :---: | :---: |
| 0 | 0 | Z to A |
| 0 | 1 | Z to B |
| 1 | 0 | Z to C |
| 1 | 1 | Z to D |

## Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

```
Storage Temperature
``` \(\qquad\)
``` \(-65^{\circ} \mathrm{C}\) to \(+150^{\circ} \mathrm{C}\)
Supply Voltage to Ground Potential -0.5 V to +2.5 V
DC Input Voltage
``` \(\qquad\)
``` -0.5 V to \(+\mathrm{V}_{\mathrm{DD}}\)
DC Output Current
``` \(\qquad\)
```

Power Dissipation ................................................................ 0.5W 120 mA

```

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

\section*{Power Supply Characteristics}
\begin{tabular}{|l|c|c|c|c|c|c|}
\hline Parameters & Description & Test Conditions \({ }^{(\mathbf{1 )}}\) & Min. \(^{\text {Typ. }}{ }^{(\mathbf{2})}\) & Max. & Units \\
\hline \(\mathrm{I}_{\mathrm{DD}}\) & Quiescent Power Supply Current & \(\mathrm{V}_{\mathrm{DD}}=\) Max., \(\mathrm{V}_{\mathrm{IN}}=\) GND or \(\mathrm{V}_{\mathrm{DD}}\) & & & 300 & \(\mu \mathrm{~A}\) \\
\hline
\end{tabular}

Notes:
1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at \(\mathrm{V}_{\mathrm{DD}}=1.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\) ambient and maximum loading.

DC Electrical Characteristics for Switching over Operating Range
\(\left(T_{A}=-40^{\circ} \mathrm{C}\right.\) to \(+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=1.8 \mathrm{~V} \pm 10 \%\) )
\begin{tabular}{|c|l|l|c|c|c|c|}
\hline Parameter & \multicolumn{1}{|c|}{ Description } & \multicolumn{1}{|c|}{ Test Conditions } & Min. & Typ. \({ }^{(2)}\) & Max. & Units \\
\hline \(\mathrm{V}_{\mathrm{IH}}\) & Input HIGH Voltage & Guaranteed HIGH level & \(0.65 \times \mathrm{V}_{\mathrm{DD}}\) & - & - & \\
\hline \(\mathrm{V}_{\mathrm{IL}}\) & Input LOW Voltage & Guaranteed LOW level & - & - & \(0.35 \times \mathrm{V}_{\mathrm{DD}}\) \\
\hline \(\mathrm{V}_{\mathrm{IK}}\) & Clamp Diode Voltage & V \\
\hline \(\mathrm{V}_{\mathrm{IH}}\) & Input HIGH Current & Max., \(\mathrm{I}_{\mathrm{IN}}=-18 \mathrm{~mA}\) & - & -0.7 & -1.2 & \\
\hline \(\mathrm{I}_{\mathrm{IL}}\) & Input LOW Current & \(\mathrm{V}_{\mathrm{DD}}=\) Max., \(\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{DD}}\) & - & - & \(\pm 5\) & \multirow{2}{*}{F} \\
\hline
\end{tabular}

Switching Characteristics ( \(\mathrm{TA}=-40^{\circ}\) to \(+85^{\circ} \mathrm{C}, \mathrm{VDD}=1.8 \mathrm{~V} \pm 10 \%\) )
\begin{tabular}{|l|l|c|c|c|c|}
\hline \multicolumn{1}{|c|}{ Parameter } & \multicolumn{1}{|c|}{ Description } & Min. & Typ. \({ }^{(2)}\) & Max. & Units \\
\hline tPZH, tPZL & Line Enable Time - SEL to AN, BN & 0.5 & - & 8.0 & \multirow{2}{c|}{ ns } \\
\hline tPHZ, tPLZ & Line Disable Time - SEL to AN, BN & 0.5 & - & 10 & \\
\hline tb-b & Bit-to-bit skew within the same differential pair & & 7 & & ps \\
\hline tch-ch & Channel-to-channel skew & & 35 & & ps \\
\hline
\end{tabular}

Notes:
1. For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

\section*{Dynamic Electrical Characteristics Over the Operating Range}
(TA \(=-40^{\circ}\) to \(+85^{\circ} \mathrm{C}, \mathrm{VDD}=1.8 \mathrm{~V} \pm 10 \%\) )
\begin{tabular}{|l|l|l|c|c|c|c|}
\hline \multicolumn{1}{|c|}{ Parameter } & \multicolumn{1}{|c|}{ Description } & Test Conditions \({ }^{(\mathbf{1 )}}\) & Min. & Typ. \(^{(\mathbf{2})}\) & Max. & Units \\
\hline \(\mathrm{X}_{\text {TALK }}\) & Crosstalk & \(\mathrm{f}=2.5 \mathrm{GHz}\) & & -40 & & dB \\
\hline \(\mathrm{O}_{\text {IRR }}\) & OFF Isolation & \(\mathrm{f}=2.5 \mathrm{GHz}\) & & -25 & & dB \\
\hline \(\mathrm{I}_{\text {LOSS }}\) & Differential Insertion Loss & \(\mathrm{f}=2.5 \mathrm{GHz}\) & & -3.0 & & dB \\
\hline BW & Bandwidth -3 dB & & & 2.6 & & GHz \\
\hline
\end{tabular}

\footnotetext{
Notes:
1. Guaranteed by design.
2. Typical values are at \(\mathrm{V}_{\mathrm{DD}}=1.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\) ambient and maximum loading.
}



Crosstalk


\section*{Off Isolation}



\section*{Test Circuit for Electrical Characteristics \({ }^{(1-5)}\)}


\section*{Switch Positions}
\begin{tabular}{|l|l|}
\hline Test & Switch \\
\hline tpLZ \(^{2}, t_{\text {PZL }}\) & \(2 \times\) V \(_{\text {DD }}\) \\
\hline\(t_{\text {PHZ }}, t_{\text {PZH }}\) & GND \\
\hline Prop Delay & Open \\
\hline
\end{tabular}

Notes:
1. \(\mathrm{C}_{\mathrm{L}}=\) Load capacitance: includes jig and probe capacitance.
2. \(\quad \mathrm{R}_{\mathrm{T}}=\) Termination resistance: should be equal to \(\mathrm{Z}_{\text {OUT }}\) of the Pulse Generator
3. Output 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
output 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
4. All input impulses are supplied by generators having the following characteristics: \(\mathrm{PRR} \leq \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{R}} \leq 2.5 \mathrm{~ns}, \mathrm{t}_{\mathrm{F}} \leq 2.5 \mathrm{~ns}\).
5. The outputs are measured one at a time with one transition per measurement.

\section*{Switching Waveforms}


Voltage Waveforms Enable and Disable Times

Package Mechanical: 42-Contact TQFN (ZH)


\section*{Ordering Information}
\begin{tabular}{|c|c|c|}
\hline Ordering Code & Package Code & Package Type \\
\hline PI2PCIE2214ZHEX & ZH & 42-Contact, Thin Fine Pitch Quad Flat No-Lead (TQFN) \\
\hline
\end{tabular}

Notes:
- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- "E" denotes Pb -free and Green
- Adding an "X" at the end of the ordering code denotes tape and reel packaging```

